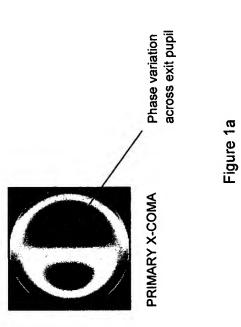
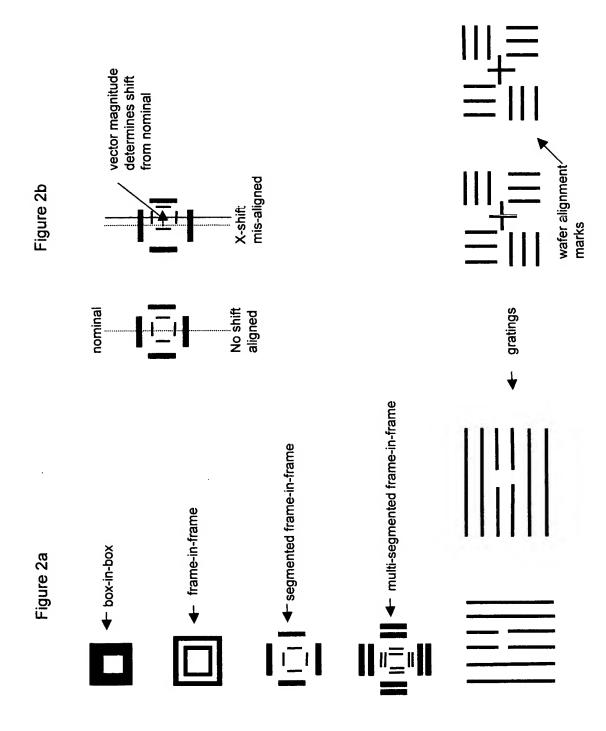


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2/23 Intrafield overlay target area Portion of overlay target Image shift due to x-coma Figure 1e Figure 1d Ideal feature position Intrafield overlay target area Airy function - no coma Figure 1c

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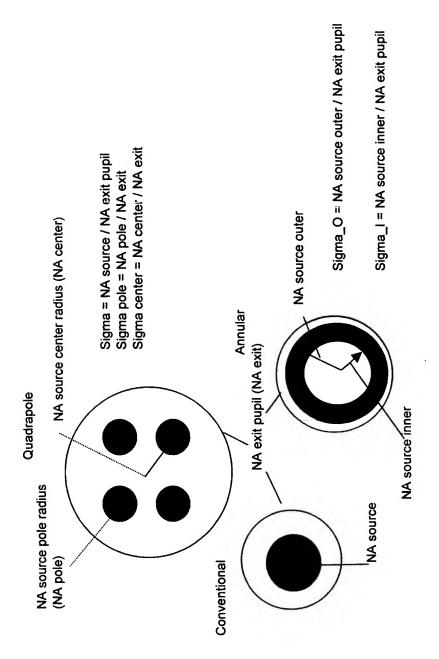


Figure 3

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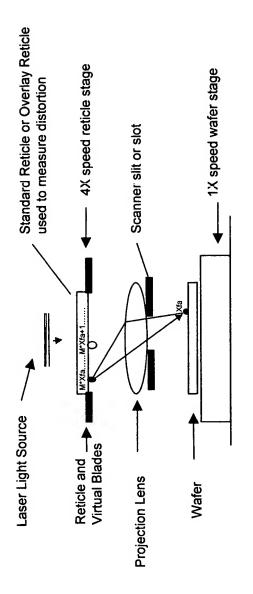
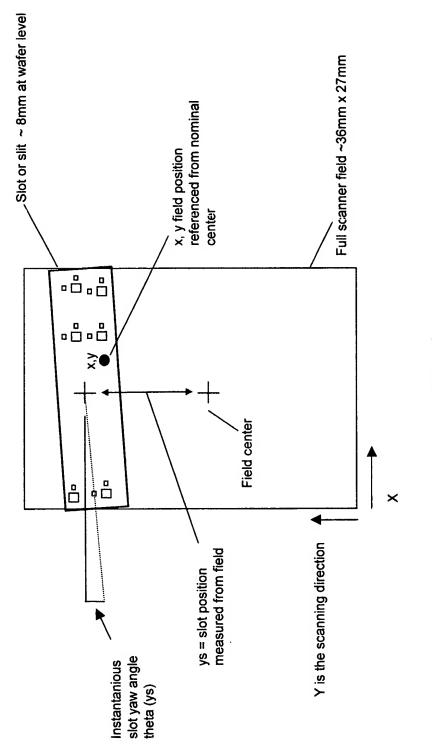


Figure 4a

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			AN	NA = 0.60, LAMBDA = 248NM	MBDA = 2	248NM			
		72.				1/			
-				<u>-</u>	-		_		
MA O	0.836	0.797	0.772		0.746	0.714	0.684	0.653	0.621
SIGMA I	0	0.239	0.309		0.373	0.428	0.479	0.522	0.559
EPS	0	0.3	0.4		0.5	9.0	2.0	0.8	6.0

EPS = fractional size of hole in source = SIGMA_I / SIGMA_0

Figure 5a

400nm resist, resist threshold model, E/E0 = 3, focus = 150nm into resist 1um space/4um pitch

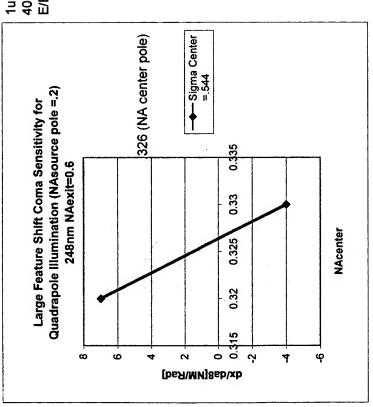


Figure 5b

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Figure 6b

Sigma Center	0.5550	0.5353	0.5250	0.5243
Sigma Pole	0.2222	0.2 0.4818 0.2222	0.2222	0.2222
e NA center	0.4995	0.4818	0.4725	0.4719
NA pol	0.5	0.2	0.2	0.2
NA exit	6.0	6.0	6.0	60
Wavelength	365nm	248nm	193nm	157nm

Center					
e Sigma	0.5450	0.5438	0.5387	0.5315	
ma Pole	33	33	33	33	
ter Sig	0.3333	0.3333	0.3333	0.3333	
NA pole NA center Sigma Pole Sigma Center	0.3270	0.3263	0.3232	0.3189	
	0.2	0.2	0.2	0.5	
NA exit	9.0	9.0	9.0	9.0	
Wavelength	365nm	248nm	193nm	157nm	

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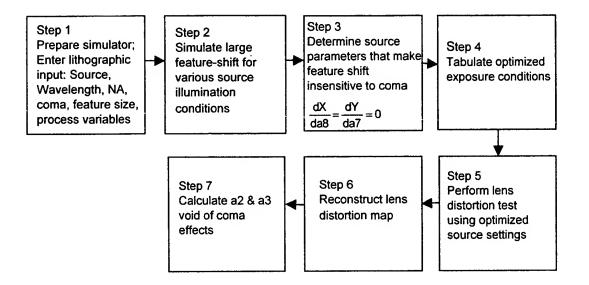


Figure 7a

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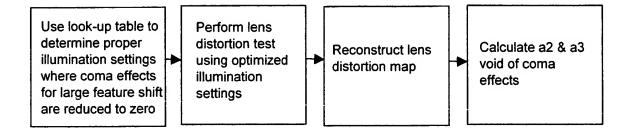
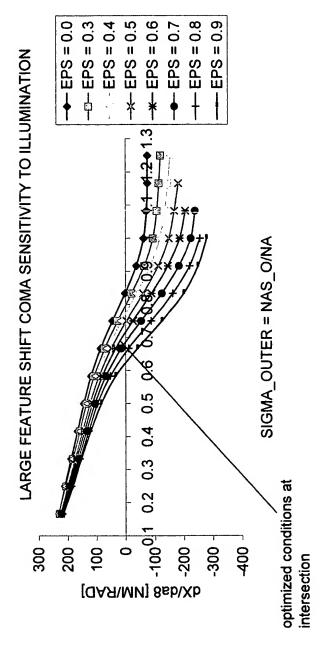


Figure 7b

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400nm resist, resist threshold model, E/E0 = 3 1um space/4um pitch focus = 150nm



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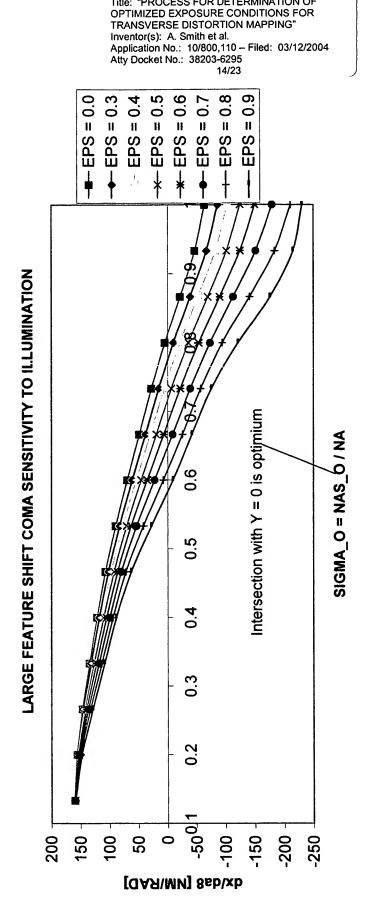
Lithography simulation conditions:

M = magnification = 4,

1um large feature on a 4um pitch Threshold resist model E/E0 = 3, 400 NM resist thickness, focus = 150nm

0.85 **ZERO COMA CONDITIONS** SIGMA_O = NAS_O / NA 0.75 0.65 0.55 0.5 0.3 0.3 AN / I_SAN = I_AMDIS

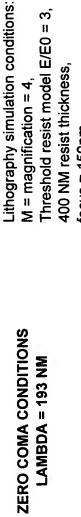
1um space/4um pitch 400nm resist, resist threshold model, E/E0 = 3, focus = 150nm



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Figure 9a

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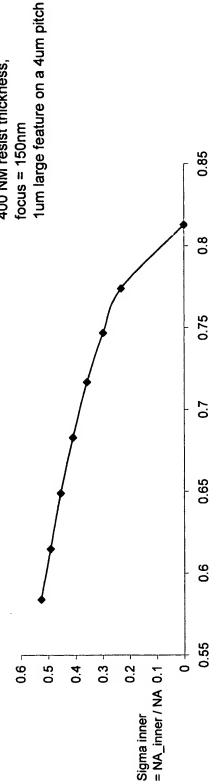


Figure 9b

Sigma outer = NA_outer / NA

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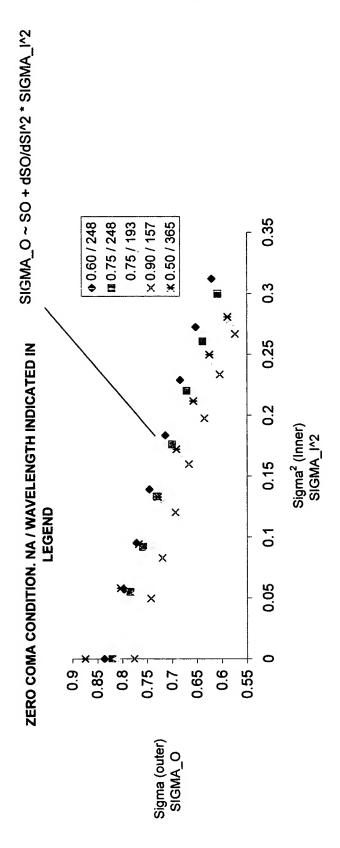


Figure 10a

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0.8

0.7

9.0

0.5

0.4

0.3

0.2

0.1

-*-dSO/dSI^2

SO, dSO/dSI^2 FUNCTION OF LAMBDA/NA

ZERO COMA CONDITION COEFFICIENTS

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0.5 -0.5 5. 7 (sigma outer) dSO/dSI^2 တ္တ ថ

λ / NA (um)

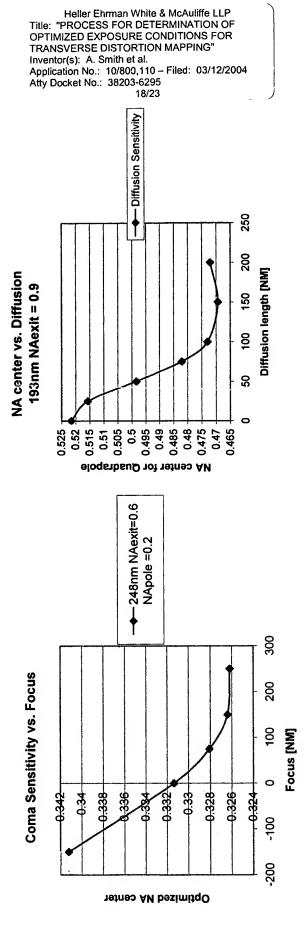
RSQ 0.9969 0.9989 0.9992 0.9974 4SO/4Slv2 -0.6808 -0.706 -0.833-0.9867 FITTING COEFFICIENTS AS FUNCTION OF LAMBDA/NA 0.8652 0.8375 0.7813 0.819 0.8233SO 0.75 0.75 0.5 0.6 0.9 LAMBDA 365 248.38 248.38 193 157 LAMBDANA [UM] 0.331173333 0.174444444 0.413966667 0.73

Figure 10c

Figure 10b

Figure 11b

Figure 11a



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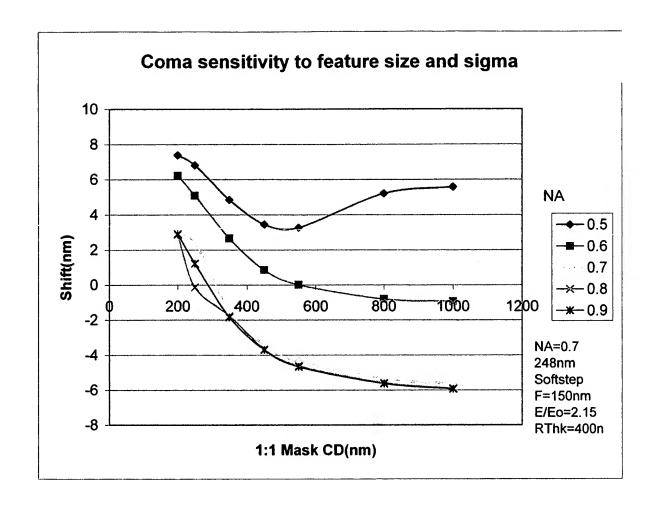
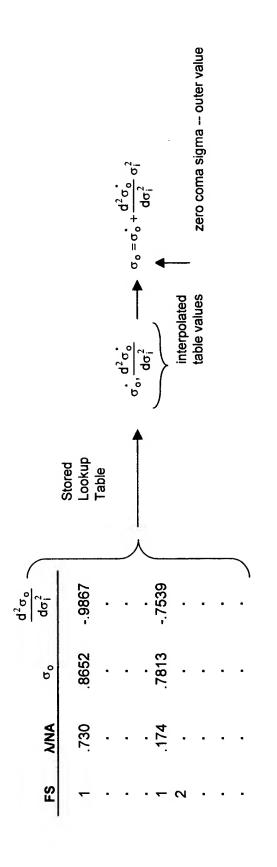


Figure 12

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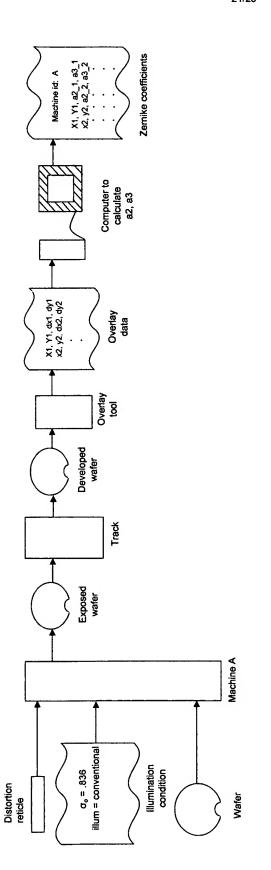
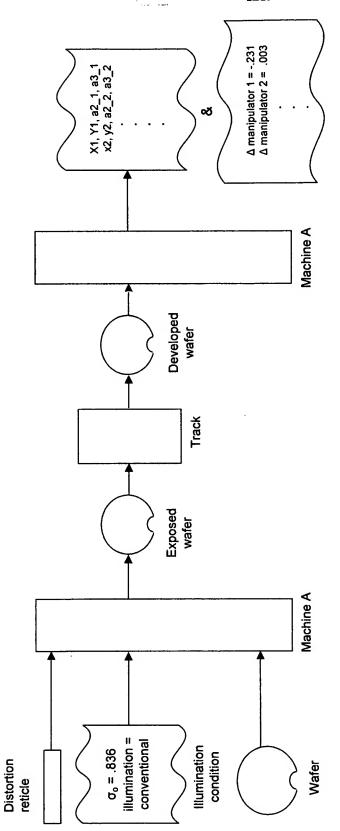


Figure 14

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